VS-400U(R) Series

Vishay Semiconductors



Standard Recovery Diodes, (Stud Version), 400 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 400 A					
Package	DO-9 (DO-205AB)				
Circuit configuration	Single				

FEATURES

- Wide current range
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC[®] types
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		400	A			
I _{F(AV)}	T _C	120	°C			
I _{F(RMS)}		630	A			
I _{FSM}	50 Hz	8250	A			
	60 Hz	8640				
l ² t	50 Hz	340	– kA²s			
141	60 Hz	311				
V _{RRM}	Range	800 to 1600	V			
TJ		-40 to +200	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA				
80		800	900					
VS-400U(R) 120		1200	1300	15				
	160	1600	1700					





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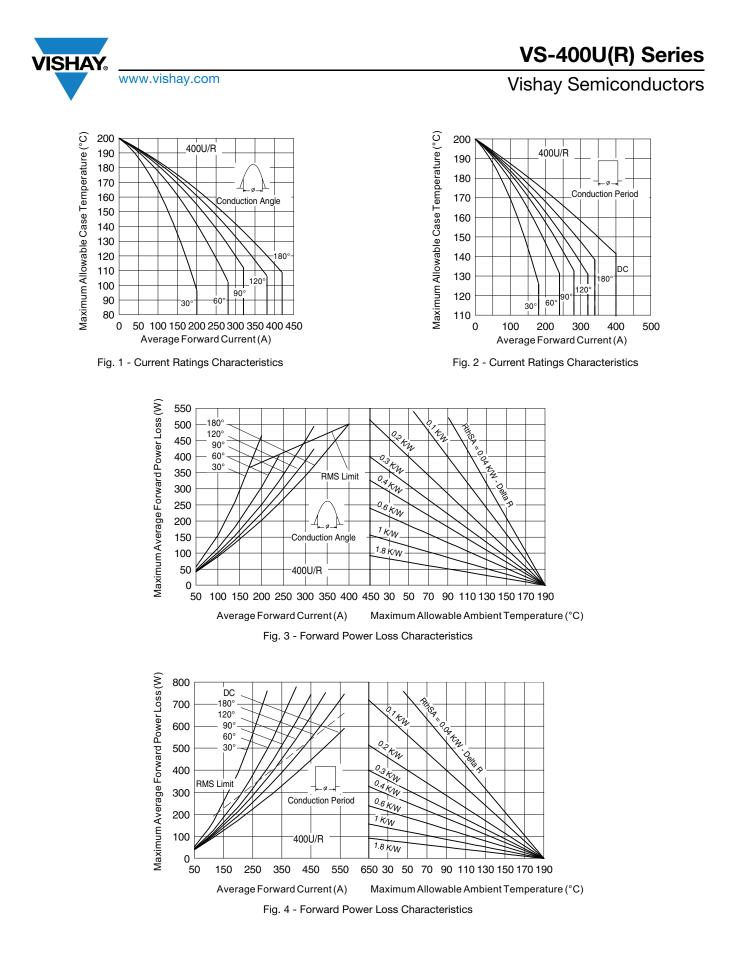
FORWARD CONDUCTION							
PARAMETER	SYMBOL		VALUES	UNITS			
Maximum average forward current	1	180° conduct	ion, half sine wa	400	А		
at case temperature	I _{F(AV)}		ion, nan sine wa	ve	120	°C	
Maximum RMS forward current	I _{F(RMS)}	DC at 110 °C	case temperatu	re	630	А	
		t = 10 ms	No voltage		8250	A	
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	8640		
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		6940		
		t = 8.3 ms	reapplied		7270	1	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		340	- kA ² s	
		t = 8.3 ms			311		
		t = 10 ms	100 % V _{RRM} reapplied		241		
		t = 8.3 ms			220		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 r	ns, no voltage re	3400	kA²√s		
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x	$I_{F(AV)} < I < \pi \times I_{F(AV)}$	0.77	v		
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}),$	T _J = T _J maximur	0.85	v		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x	$I_{F(AV)} < I < \pi \times I_{F(AV)}$	0.49	mΩ		
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}),$	T _J = T _J maximur	0.49	1115.2		
Maximum forward voltage drop	V _{FM}	I _{pk} = 1500 A, 7	J = TJ maximum	, t _p = 10 ms sinusoidal wave	1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-40 to 200	°C	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased 0.04		r./ vv	
Maximum allowed mounting torque \pm 10 %		Not lubricated threads	27	N·m	
Approximate weight			250	g	
Case style		See dimensions - link at the end of datasheet DO-9 (DO-205AB)			

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.020	0.013				
120°	0.023	0.023				
90°	0.029	0.031	$T_J = T_J maximum$	K/W		
60°	0.042	0.044				
30°	0.073	0.074				

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC





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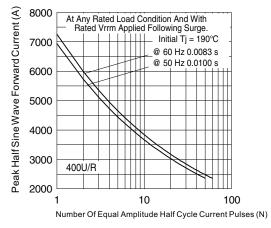


Fig. 5 - Maximum Non-Repetitive Surge Current

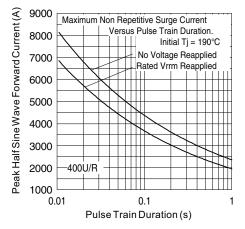


Fig. 6 - Maximum Non-Repetitive Surge Current

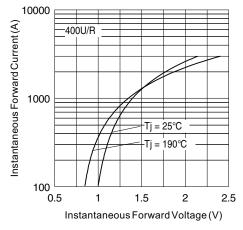
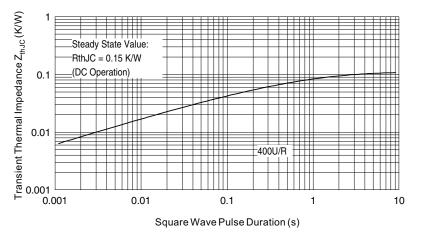


Fig. 7 - Forward Voltage Drop Characteristics





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ORDERING INFORMATION TABLE

Device code	vs-	40	0	U	R	160	D
		2	3	4	5	6	7
	1 -	- Vish	ay Sem	iconduc	tors pro	duct	
	2 -	40 =	essenti	al part r	number		
	3 -	0 = 9	standard	l recove	ry devic	ce	
	4 -	- U =	stud nor	mal pol	arity (ca	thode to	o stud)
	5 -	• No	one = sti	ud norm	al polar	ity (cath	ode to
		• R	= stud re	everse p	olarity	(anode	to stud)
	6 -	Volta	age cod	e x 10 =	V _{RRM} (see Vol	tage Ra
	7 -	Diffu	ised dio	de			

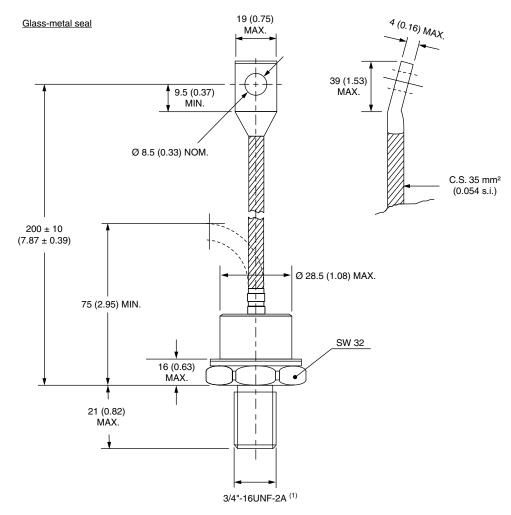
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95339			

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DO-205AB (DO-9) for 400U(R) Series

DIMENSIONS in millimeters (inches)



Note

• For metric device: M16 x 1.5 contact factory



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